

TOSHIBA Transistor Silicon NPN Triple Diffused Type (PCT process)

# 2SC3515

HIGH Voltage Control Applications  
 Plasma Display, Nixie Tube Driver Applications  
 Cathode Ray Tube Brightness Control Applications

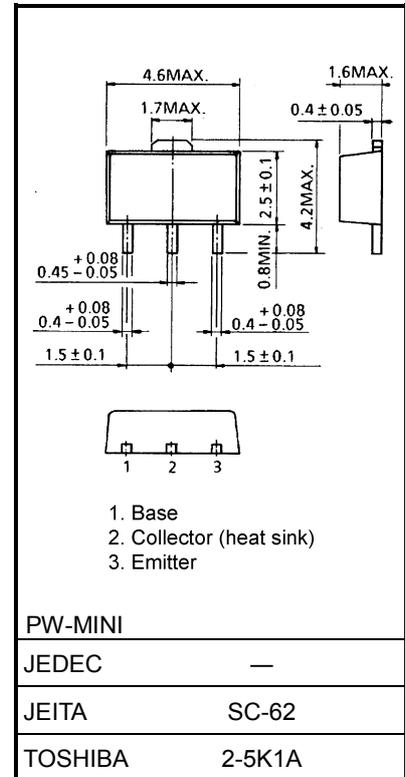
- High voltage:  $V_{CBO} = 300\text{ V}$ ,  $V_{CEO} = 300\text{ V}$
- Low saturation voltage:  $V_{CE(sat)} = 0.5\text{ V (max)}$
- Small collector output capacitance:  $C_{ob} = 3\text{ pF (typ.)}$
- Complementary to 2SA1384
- Small flat package
- $P_C = 1.0\text{ to }2.0\text{ W}$  (mounted on ceramic substrate)

### Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	300	V
Collector-emitter voltage	$V_{CEO}$	300	V
Emitter-base voltage	$V_{EBO}$	6	V
Collector current	$I_C$	100	mA
Base current	$I_B$	20	mA
Collector power dissipation	$P_C$	500	mW
	$P_C$ (Note 1)	1000	
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55 to 150	$^\circ\text{C}$

Note 1: Mounted on ceramic substrate ( $250\text{ mm}^2 \times 0.8\text{ mm}$ )

Unit: mm



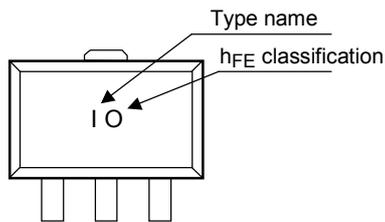
Weight: 0.05 g (typ.)

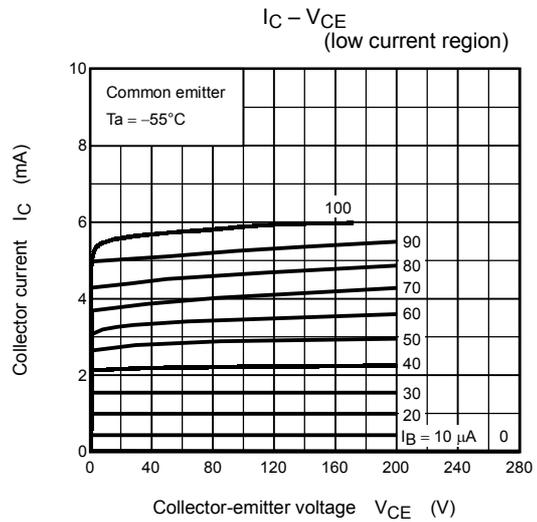
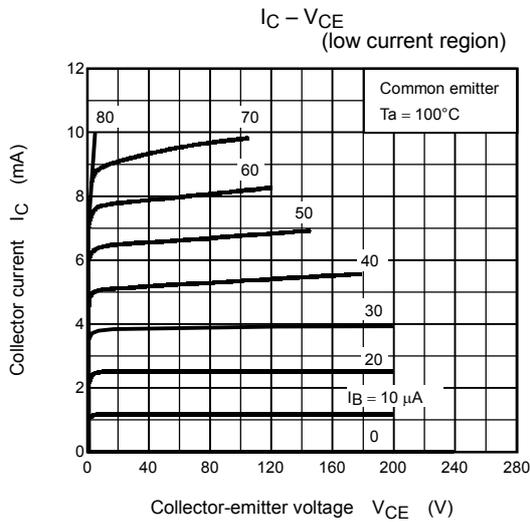
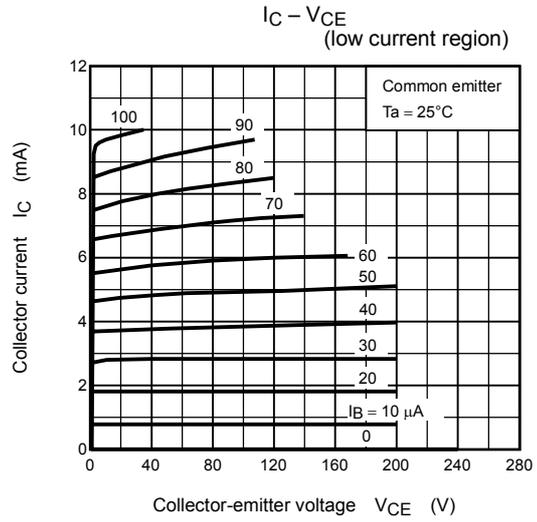
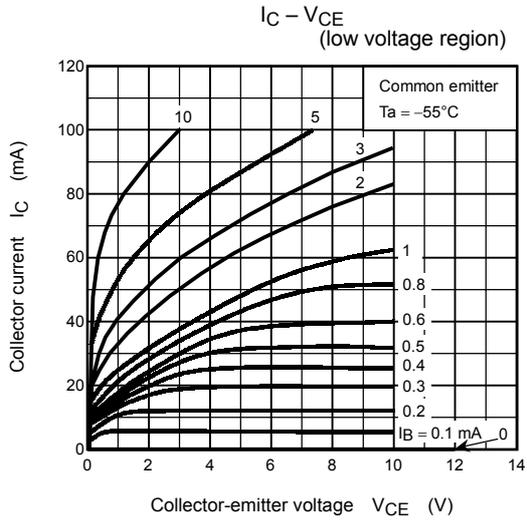
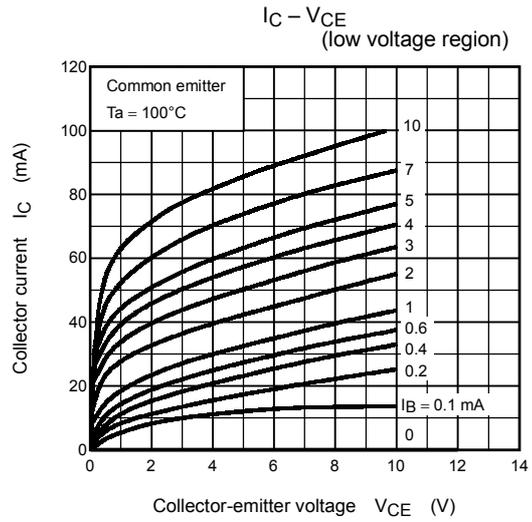
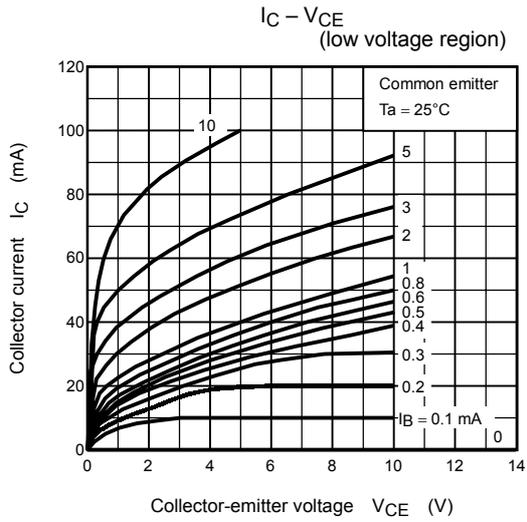
## Electrical Characteristics (Ta = 25°C)

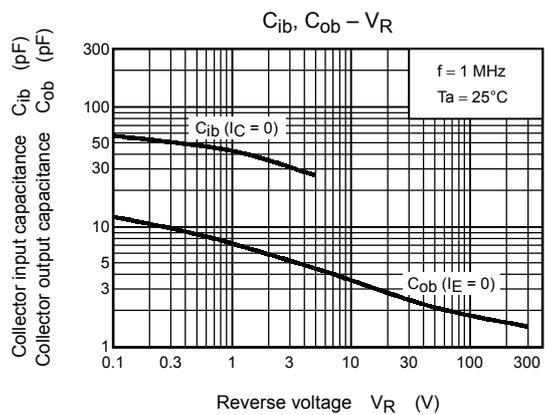
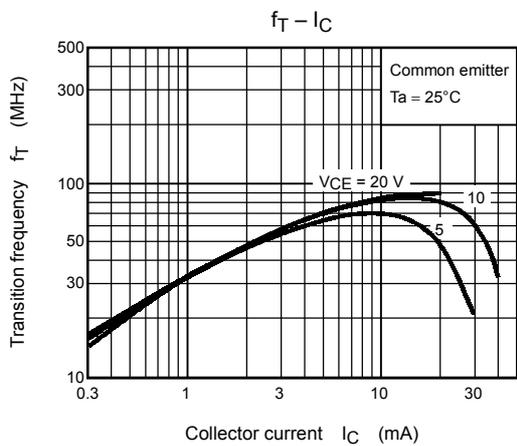
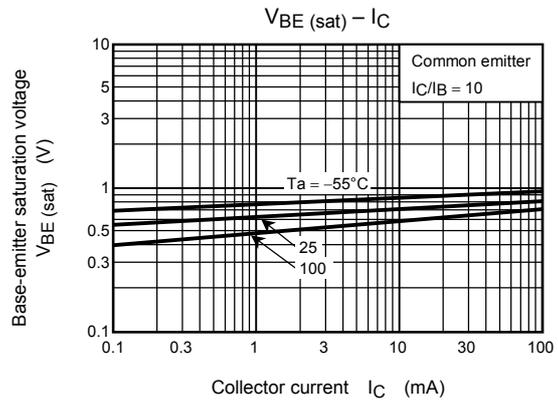
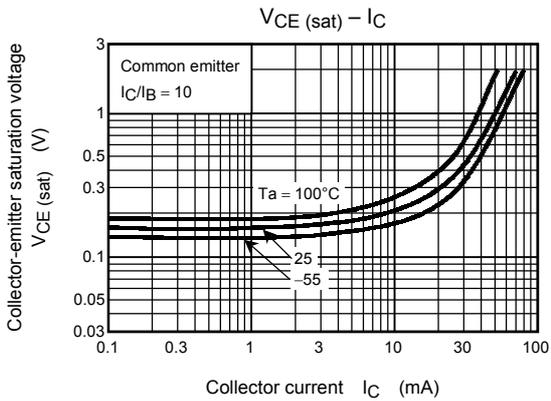
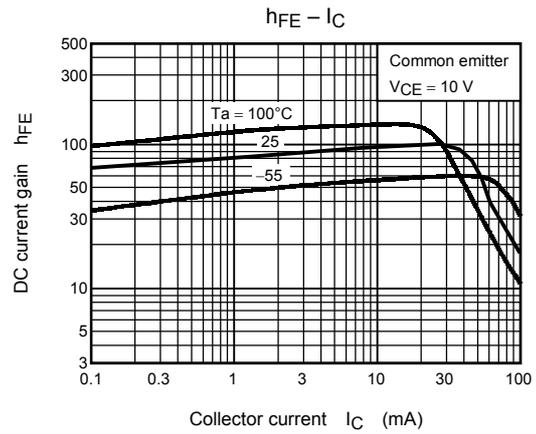
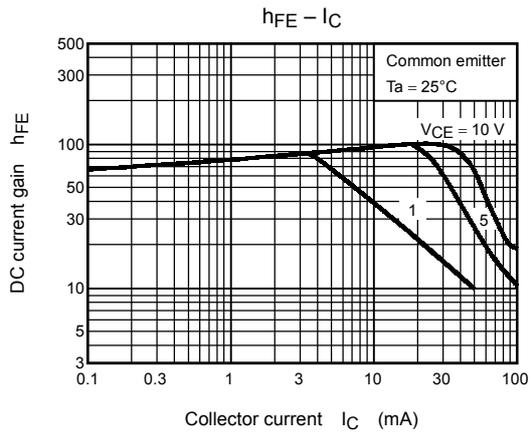
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	$I_{CBO}$	$V_{CB} = 300\text{ V}, I_E = 0$	—	—	0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = 6\text{ V}, I_C = 0$	—	—	0.1	$\mu\text{A}$
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 0.1\text{ mA}, I_E = 0$	300	—	—	V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 1\text{ mA}, I_B = 0$	300	—	—	V
DC current gain	$h_{FE(1)}$ (Note 2)	$V_{CE} = 10\text{ V}, I_C = 20\text{ mA}$	30	—	150	—
	$h_{FE(2)}$	$V_{CE} = 10\text{ V}, I_C = 20\text{ mA}$	20	—	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 20\text{ mA}, I_B = 2\text{ mA}$	—	—	0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 20\text{ mA}, I_B = 2\text{ mA}$	—	—	1.0	V
Transition frequency	$f_T$	$V_{CE} = 10\text{ V}, I_C = 20\text{ mA}$	50	80	—	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = 20\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	3	4	pF

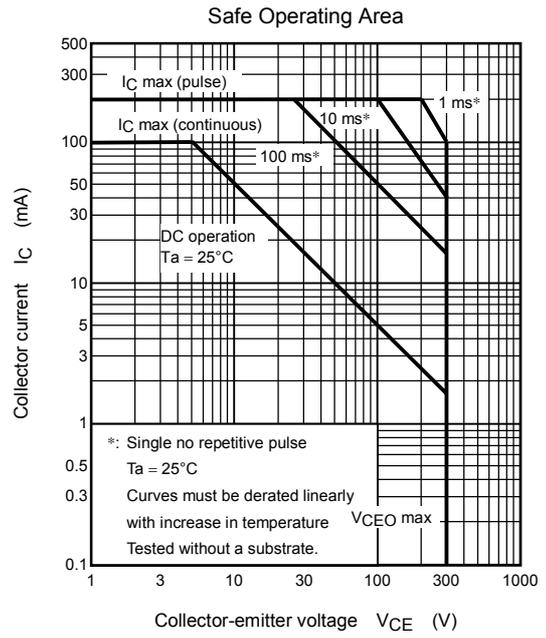
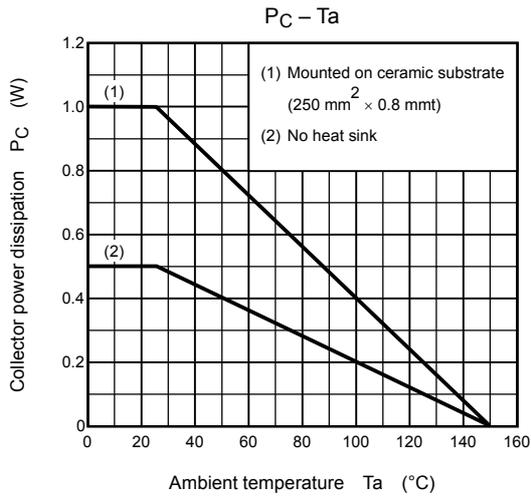
Note 2:  $h_{FE(1)}$  classification R: 30 to 90, O: 50 to 150

## Marking









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